

RECEIVED  
CENTRAL FAX CENTER

NOV 18 2005

Docket No.: 2336-257

PATENT

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Seung Wan CHAE *et al.*

U.S. Patent Application No. 10/811,808

Filed: March 30, 2004

Confirmation No. 2845

Group Art Unit: 2814

Examiner: Wai Sing Louie

For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE AND METHOD  
FOR MANUFACTURING THE SAME

Dear Sir:

Transmitted herewith is an Amendment in the above identified application.

- ☒ No additional fee is required.
- ☐ Small entity status of this application has been established.
- ☐ Also attached:

BEST AVAILABLE COPY

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	3	20	0	x \$ 50 =	\$0
Independent Claims	1	3	0	x \$200 =	\$0
If multiple claims newly presented, add \$360.00					-----
Fee for extension of time					-----
TOTAL FEE DUE					\$0

- ☐ A credit card authorization form in the amount of \_\_\_\_\_ is attached
- ☒ The Commissioner is hereby authorized to charge payment of any *deficiency* in fees associated with this communication or credit any overpayment, to Deposit Account No. 07-1337, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

LOWE HAUPTMAN &amp; BERNER, LLP

Benjamin J. Hauptman  
Registration No.: 29,310USPTO Customer No. 22429  
1700 Diagonal Road, Suite 300  
Alexandria, Virginia 22314  
(703) 684-1111 BJH/klb  
(703) 518-5499 Facsimile  
Date: November 18, 2005CERTIFICATION OF FACSIMILE TRANSMISSION  
I HEREBY CERTIFY THAT THIS PAPER IS BEING FACSIMILE TRANSMITTED  
TO THE PATENT AND TRADEMARK OFFICE ON THE DATE SHOWN BELOWTYPE OR PRINT NAME OF PERSON SIGNING CERTIFICATION  
*Kindra Bryant*

SIGNATURE

November 18, 2005  
DATE571-273-8300  
FACSIMILE NUMBER

RECEIVED  
CENTRAL FAX CENTER  
NOV 18 2005

Docket No.: 2336-257

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Seung Wan CHAE *et al.*

U.S. Patent Application No. 10/811,808

Filed: March 30, 2004

:  
:  
: Confirmation No. 2845  
:  
: Group Art Unit: 2814  
:  
: Examiner: Wai Sing Louie

For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE  
AND METHOD FOR MANUFACTURING THE SAME

AMENDMENT

COMMISSIONER FOR PATENTS  
P.O. Box 1450  
Alexandria VA 22313-1450

BEST AVAILABLE COPY

Sir:

The following amendments and remarks are submitted in response to the Official Action  
dated *November 18, 2005*.

CERTIFICATION OF FACSIMILE TRANSMISSION  
I HEREBY CERTIFY THAT THIS PAPER IS BEING FACSIMILE TRANSMITTED  
TO THE PATENT AND TRADEMARK OFFICE ON THE DATE SHOWN BELOW

\_\_\_\_\_  
Type or Print Name of Person Signing Certification

SIGNATURE

\_\_\_\_\_  
November 18, 2005  
DATE

\_\_\_\_\_  
571-273-8300  
FACSIMILE NUMBER